

The 2010 International Meeting for Future of Electron Devices, Kansai (IMFEDK2010) のご案内

日時: 2010年5月13日(木) ~ 5月14日(金) / May 13-14, 2010

場所: 関西大学 100周年記念会館 /

Kansai University Centenary Memorial Hall, Osaka, Japan

URL: <http://www.imfedk.org/>

(Official Language: English)

■ Keynote Speeches

[May 13, pm]

- [1] "Advanced Electronics for Medical Applications (Tentative)",
Manami Tanaka (AIST)
- [2] "Electron Devices of IRT (Information and Robot Technology) in Aging Society",
Isao Shimoyama (The University of Tokyo)

[May 14, am]

- [3] "Future Prospects of Nano-Scale Transistors for VLSI Applications",
Toshiro Hiramoto (The University of Tokyo)

■ Invited Papers for the Special Session [May 14, pm]

- [1] "Current Controllability and Stability in Multi-Mesa-Channel AlGaN/GaN HEMTs",
T. Hashizume and K. Ohi (Hokkaido University and JST-CREST)
- [2] "Integrated MEMS Sensors (Tentative)",
Masafumi Kimata (Ritsumeikan University)

■ Tutorials (in Japanese) [May 13, am]

- [1] "酸化亜鉛の結晶成長とデバイス応用", 佐々 誠彦 (大阪工業大学)
- [2] "CMOS-LSI 低電力化技術", 篠原 尋史 (STARC)